

PNZ202S (PN202S)

Silicon planar type

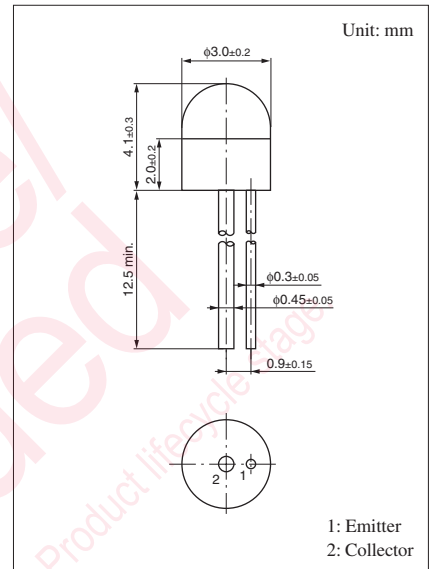
For optical control systems

■ Features

- Darlington output, high sensitivity
- Easy to combine with red and infrared light emitting diodes
- Small size ($\phi 3$) ceramic package

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-emitter voltage (Base open)	V_{CEO}	20	V
Emitter-collector voltage (Base open)	V_{ECO}	5	V
Collector current	I_C	30	mA
Collector power dissipation	P_C	100	mW
Operating ambient temperature	T_{opr}	-25 to +80	$^\circ\text{C}$
Storage temperature	T_{stg}	-30 to +100	$^\circ\text{C}$



■ Electrical-Optical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Photocurrent ^{*1, *2}	$I_{CE(L)}$	$V_{CE} = 10\text{ V}, L = 2\text{ lx}$	0.2		5.0	mA
Dark current	I_{CEO}	$V_{CE} = 10\text{ V}$		0.1	0.5	μA
Peak emission wavelength	λ_p	$V_{CE} = 10\text{ V}$		800		nm
Half-power angle	θ	The angle from which photocurrent becomes 50%		30		$^\circ$
Rise time ^{*3}	t_r	$V_{CC} = 10\text{ V}, I_{CE(L)} = 5\text{ mA}, R_L = 100\ \Omega$		150		μs
Fall time ^{*3}	t_f			150		μs
Collector-emitter saturation voltage ^{*1}	$V_{CE(sat)}$	$I_{CE(L)} = 1\text{ mA}, L = 100\text{ lx}$		0.7	1.5	V

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.

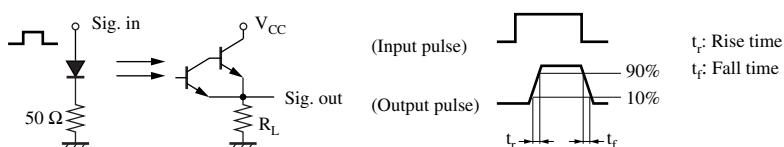
3. This device is designed be disregarded radiation.

5. *1: Source: Tungsten (color temperature 2856 K)

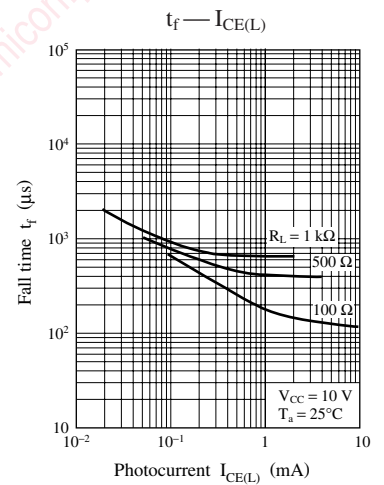
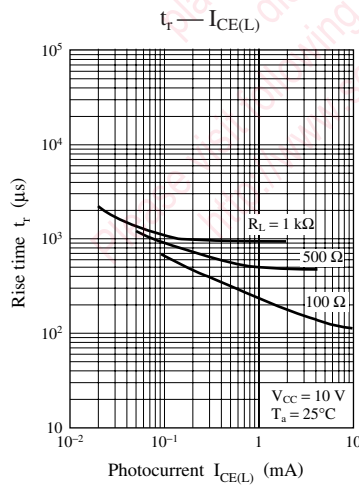
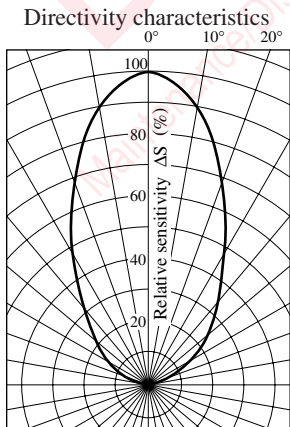
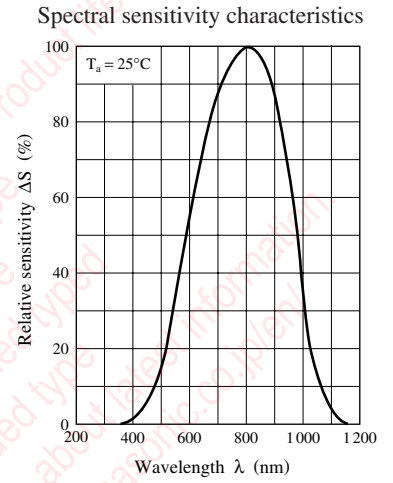
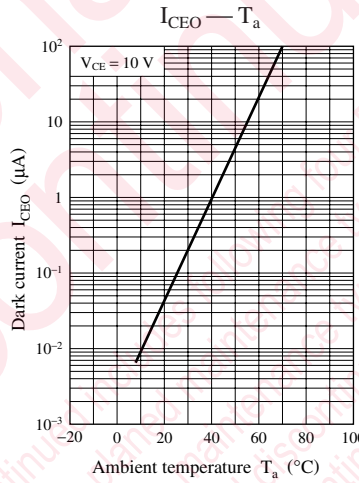
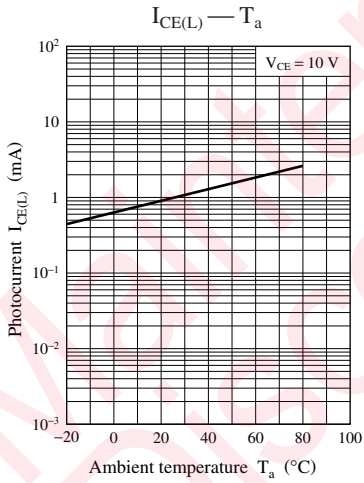
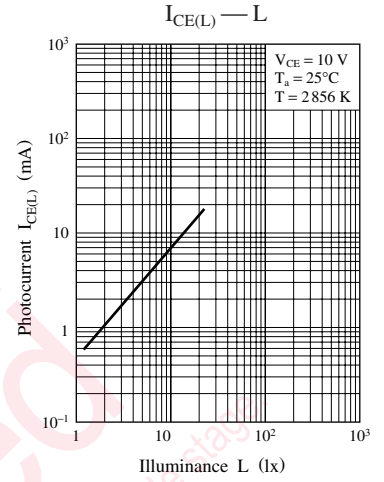
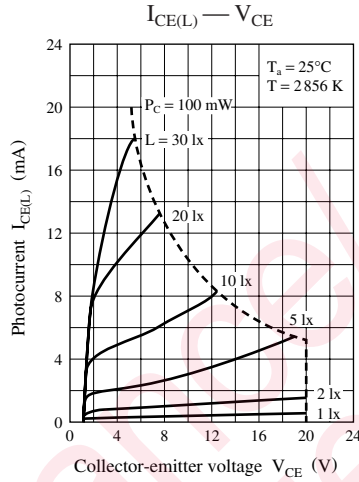
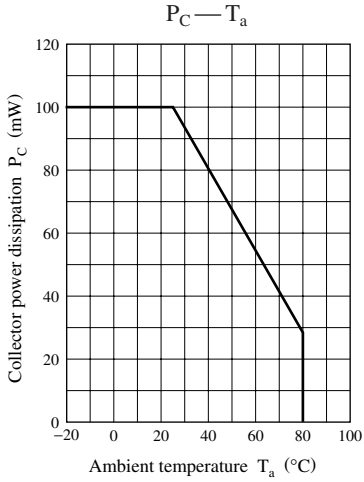
*2: Rank classification

Rank	QL	RL	SL
$I_{CE(L)}$ (mA)	0.2 to 0.8	0.6 to 1.65	1.35 to 5.0
Color	—	Red	—

*3: Switching time measurement circuit



Note) The part number in the parenthesis shows conventional part number.



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